

# GaAs IC SPDT Switch Non-Reflective DC–6 GHz



AS006M2-93

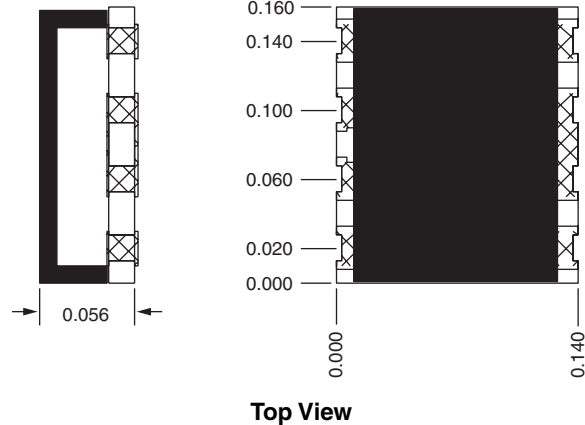
## Features

- Low DC Power Consumption
- High Isolation, Non-Reflective
- Broadband DC–6 GHz
- Excellent Intermodulation Products
- Small Low Cost “Chip on Board” Package

## Description

The AS006M2-93 is an IC FET SPDT switch in a low cost “chip on board” package. It features non-reflective matching at each output, broadband performance, with very low DC power consumption. This switch can be used in many analog and digital wireless communication systems.

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## Electrical Specifications at 25°C

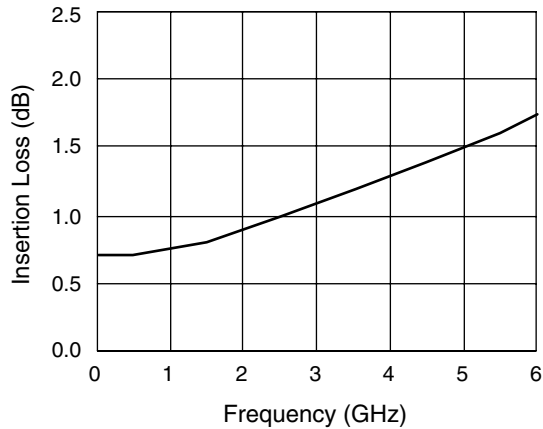
Parameter <sup>1</sup>	Frequency <sup>4</sup>	Min.	Typ.	Max.	Unit
Insertion Loss <sup>2</sup>	DC–1.0 GHz		0.7	0.8	dB
	DC–2.0 GHz		1.0	1.2	dB
	DC–4.0 GHz		1.4	1.6	dB
	DC–6.0 GHz		1.8	2.0	dB
Isolation	DC–1.0 GHz	48	58		dB
	DC–2.0 GHz	42	50		dB
	DC–4.0 GHz	36	42		dB
	DC–6.0 GHz	26	35		dB
VSWR (I/O)	DC–1.0 GHz		1.3:1	1.4:1	
	DC–2.0 GHz		1.4:1	1.6:1	
	DC–4.0 GHz		1.6:1	1.8:1	
	DC–6.0 GHz		1.8:1	2.0:1	

## Operating Characteristics at 25°C

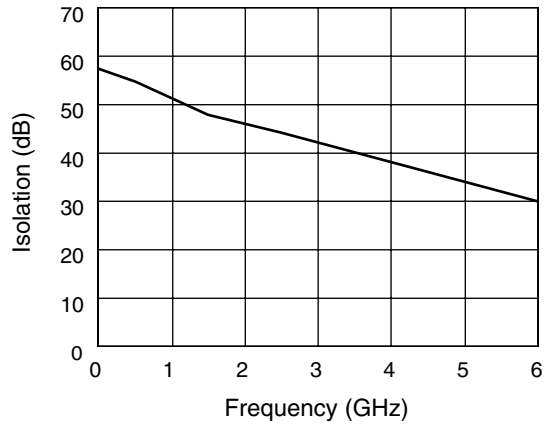
Parameter	Condition	Frequency	Min.	Typ.	Max.	Unit
Switching Characteristics	Rise, Fall (10/90% or 90/10% RF)			3		ns
	On, Off (50% CTL to 90/10% RF)			6		ns
	Video Feedthru <sup>3</sup>			15		mV
Input Power for 1 dB Compression		0.50–6 GHz		24		dBm
		0.05 GHz		16		dBm
Intermodulation Intercept Point (IP3)	For Two-tone Input Power 13 dBm	0.50–6 GHz		46		dBm
Control Voltages	$V_{Low} = 0 \text{ to } -0.2 \text{ V @ } 20 \mu\text{A Max.}$ $V_{High} = -5 \text{ V @ } 50 \mu\text{A to } -8 \text{ V @ } 200 \mu\text{A Max.}$					

1. All measurements made in a 50 Ω system, unless otherwise specified.
2. Insertion loss changes by 0.003 dB/°C.
3. Video feedthru measured with 1 ns risetime pulse and 500 MHz bandwidth.
4. DC = 300 kHz.

### Typical Performance Data



Insertion Loss vs. Frequency



Isolation vs. Frequency

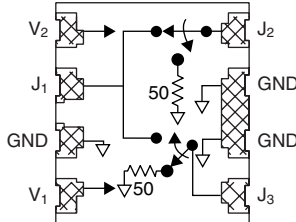
### Truth Table

V <sub>1</sub>	V <sub>2</sub>	J <sub>1</sub> -J <sub>2</sub>	J <sub>1</sub> -J <sub>3</sub>
-5	0	Insertion Loss	Isolation
0	-5	Isolation	Insertion Loss

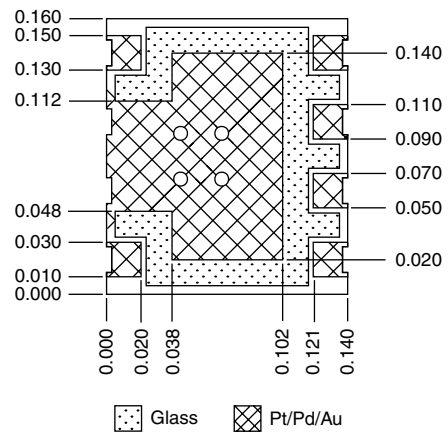
### Absolute Maximum Ratings

Characteristic	Value
RF Input Power (RF In)	2 W Max. > 500 MHz 0/-8 V Control
Control Voltage (V <sub>C</sub> )	-0.2 V, -10 V
Operating Temperature (T <sub>OP</sub> )	-40°C to +90°C
Storage Temperature (T <sub>ST</sub> )	-65°C to +150°C
Thermal Resistance (Θ <sub>JC</sub> )	25°C/W

### Pin Out



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Bottom View

The “chip on board” package is a ceramic leadless chip carrier with a ceramic lid, which allows for automatic pick and place. The external terminals and backside ground plane are Pt/Pd/Au, which is highly leach resistant and very tolerant to variations in solder conditions. The glass fingers between contacts prevent the possibility of shorted terminals. The recommended solder attachment is a SN6337 (Pb/SN).